# DR-AN-20-MO

20 GHz Analog Driver

The DR-AN-20-MO is a wideband RF amplifier module designed for analog applications at frequencies up to 20 GHz.

The DR-AN-20-MO is characterized by a low Noise Figure and a linear transfer function whose 1 dB compression point is above 20 dBm. It exhibits flat Group Delay and Gain curve with reduced ripple over the entire bandwidth.

The DR-AN-20-MO comes in a compact 52 mm x 25.6 mm housing with K type RF connectors (compatible SMA) and with an optional heat-sink. It operates from a single power supply for safety and ease of use, and offers gain control over 3 dB.



This amplifier module is ideally suited to drive optical modulators for analog applications.

#### **FEATURES**

- Output voltage up to 9 V<sub>nn</sub>
- · Linear amplifier
- Flat gain up to 20 GHz
- · Single voltage power supply
- · Low group delay variation

#### **APPLICATIONS**

- LiNbO modulators
- · Linear amplification

2 1.5 0 3 0 0.0 0.0
OFDM, RF over Fiber

### Research & Development

#### **OPTIONS**

· Heat-sink

### **Performance Highlights**

Parameter	Min	Тур	Max	Unit
Cut-off frequencies	50 k	20 G	-	Hz
Output voltage	0	-	9	$V_{pp}$
Gain	28	30	<u> </u>	dB
Saturated output power	23	- 175	-	dBm
Output power 1 dB comp	20	21	-	dB
Harmonics	- /	()-	-15	dBc
Noise figure	5	-	7	dB

Measurements for  $V_{bias} = 12 \text{ V}$ ,  $V_{amp} = 1.2 \text{ V}$ ,  $I_{bias} = 305 \text{ mA}$ 

网址: www.bonphot.com 邮箱: sales@bonphot.com 电话: 0512-62828421

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### **DC Electrical Characteristics**

Parameter		Symbol	Min	Тур	Max	Unit
Supply voltage (fixed)		V <sub>bias</sub>	-	12	-	V
Current consumption		l <sub>bias</sub>	-	310	-	mA
Gain control voltage		$V_{amp}$	-	1.2	-	V

#### **Electrical Characteristics**

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Lower frequency	f <sub>3db</sub> , lower	-3 dB point	-	-	50	kHz
Upper frequency	f <sub>3db</sub> , upper	-3 dB point	18	20	-	GHz
Gain	S <sub>21</sub>	Small signal, f < 15 GHz	28	30	-	dB
Gain ripple	- 7	f < 15 GHz	1-2	-	± 1.5	dB
Input return loss	S <sub>11</sub>	f < 10 GHz	XL-Y	-10	-	dB
Output return loss	S <sub>22</sub>	f < 20 GHz	37-	-10	-	dB
Isolation	S <sub>12</sub>	f < 20 GHz	-	-60	-	dB
Output power 1 dB	P <sub>1 dB</sub>	2 GHz < f < 16 GHz	20	21	-	dBm
Saturated output power	P <sub>sat</sub>	2 GHz < f < 12 GHz	23	-	-	dBm
Output voltage	$V_{out}$	Linear	0	-	7	$V_{pp}$
		Maximum swing	0	ح ۱ ا ح	9	
Noise figure	NF	f < 7 GHz & f > 18 GHz	5	13/4	7	dB
		7 GHz < f < 18 GHz	3		5	
Harmonics	Harm	@P <sub>1 dB'</sub> f < 5 GHz	- XX	-	-15	dBc
Power dissipation	Р	Small signal	7 <del>-</del> X	3.6	5.2	W

Conditions: S parameters -30 dBm,  $T_{amb}$  = 25°C, 50  $\Omega$  system

### **Absolute Maximum Ratings**

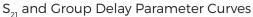
Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

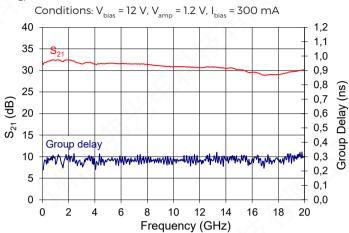
Parameter	Symbol	Min	Max	Unit	
RF input voltage	$V_{in}$	(1) 2	0.6	$V_{pp}$	
Supply voltage	$V_{bias}$	0	13	V	
DC current	l <sub>bias</sub>	0	400	mA	
Gain control voltage	$V_{\sf amp}$	0	1.3	V	
Power dissipation	$P_{diss}$	-	5.2	W	
Operating temperature	T <sub>op</sub>	0	+40	°C	
Storage temperature	$T_{st}$	-10	+70	°C	

**iXblue** 

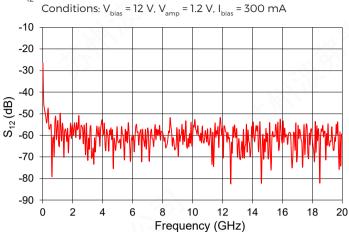
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### DR-AN-20-MO



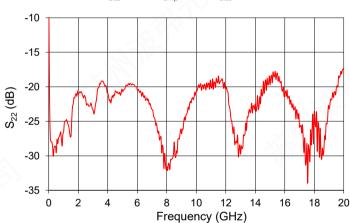






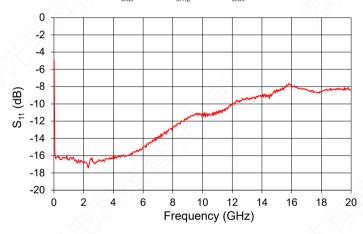
### S<sub>22</sub> Parameter Curve





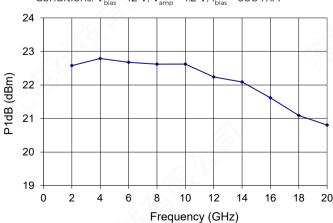
### S<sub>11</sub> Parameter Curve

Conditions:  $V_{bias} = 12 \text{ V}$ ,  $V_{amp} = 1.2 \text{ V}$ ,  $I_{bias} = 300 \text{ mA}$ 



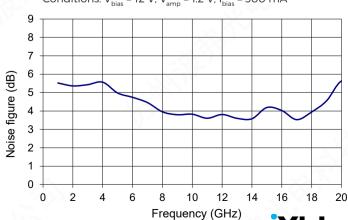
#### Saturated Output Power Curve

Conditions:  $V_{bias} = 12 \text{ V}$ ,  $V_{amp} = 1.2 \text{ V}$ ,  $I_{bias} = 300 \text{ mA}$ 



### Noise Figure Curve

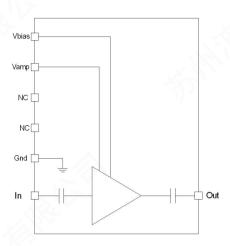
Conditions:  $V_{bias} = 12 \text{ V}$ ,  $V_{amp} = 1.2 \text{ V}$ ,  $I_{bias} = 300 \text{ mA}$ 



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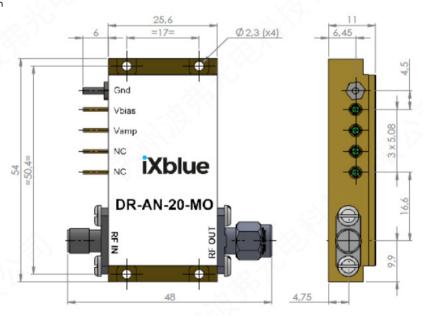
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### Electrical Schematic Diagram



### Mechanical Diagram and Pinout

All measurements in mm





The heat-sinking of the module is necessary. It's user responsability to use an adequate heat-sink. Refer to page 5 for iXblue recommended heat-sink.

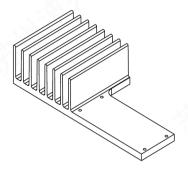
PIN	Function	Unit	
IN	RF In	Female K connector	
OUT	RF Out	Male K connector	
$V_{\text{bias}}$	Power supply voltage	Set a typical operating specification	
V <sub>amp</sub>	Output voltage amplitude adjustment	Adjust for gain control tuning	

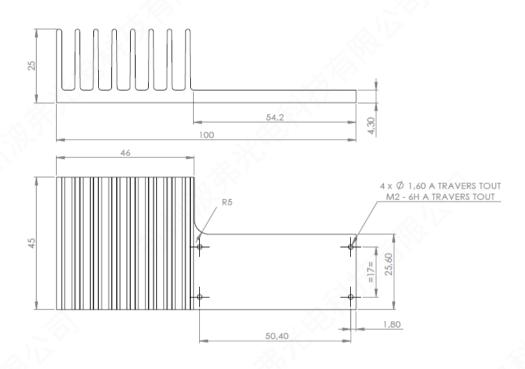
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### Mechanical Diagram and Pinout with HS-MO2 Heat-sink

All measurements in mm





#### **About us**

iXblue Photonics produces specialty optical fibers and Bragg gratings based fiber optics components and provides optical modulation solutions based on the company lithium niobate (LiNbO<sub>3</sub>) modulators and RF electronic modules. iXblue Photonics serves a wide range of industries: sensing and instruments, defense, telecommunications, space and fiber lasers as well as research laboratories all over the world.

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02 2022 ED3 / SP-0028-PR-04